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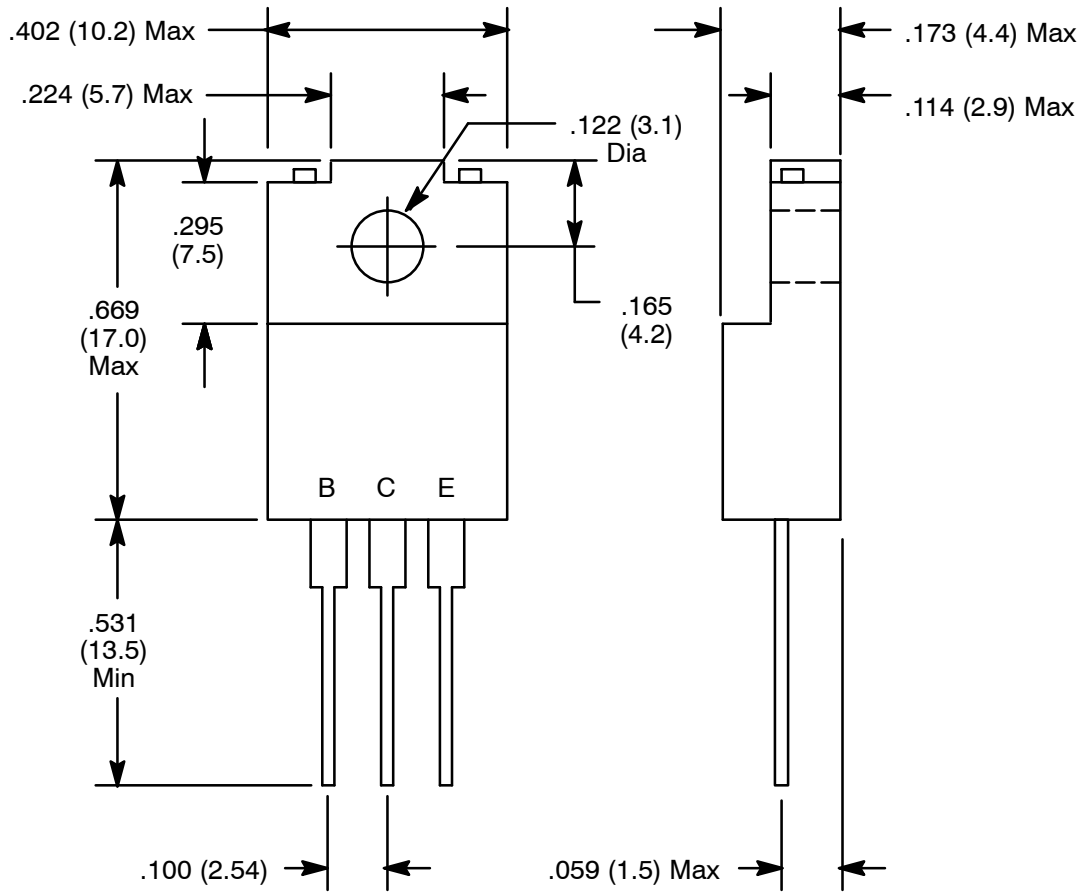
## NTE2576 (NPN) & NTE2577 (PNP) Silicon Complementary Transistors Audio Output Driver TO220F Full Pack

**Absolute Maximum Ratings:** ( $T_A = +25^\circ\text{C}$  unless otherwise specified)

Collector–Base Voltage, $V_{CBO}$ .....	200V
Collector–Emitter Voltage, $V_{CEO}$ .....	200V
Emitter–Base Voltage, $V_{EBO}$ .....	6V
Collector Current, $I_C$ .....	2A
Base Current, $I_B$ .....	1A
Power Dissipation ( $T_C = +25^\circ\text{C}$ ), $P_C$ .....	20W
Operating Junction Temperature, $T_J$ .....	+150°C
Storage Temperature Range, $T_{stg}$ .....	–55° to +150°C

**Electrical Characteristics:** ( $T_A = +25^\circ\text{C}$  unless otherwise specified)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Collector Cutoff Current	$I_{CBO}$	$V_{CB} = 180V$	–	–	10	° A
Emitter Cutoff Current	$I_{EBO}$	$V_{EB} = 6V$	–	–	10	° A
Collector–Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C = 10mA$	180	–	–	V
DC Current Gain	$h_{FE}$	$V_{CE} = 10V, I_C = 700mA$	60	–	240	
Collector–Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C = 700mA, I_B = 70mA$	–	–	1.0	V
Transition Frequency	$f_T$	$V_{CE} = 12V, I_E = 700mA$	–	60	–	MHz
Output Capacitance	$C_{ob}$	$V_{CB} = 10V, f = 1MHz$	–	30	–	pF



**NOTE:** Tab is isolated